TOSHIBA Field Effect Transistor Silicon N Channel Junction Type

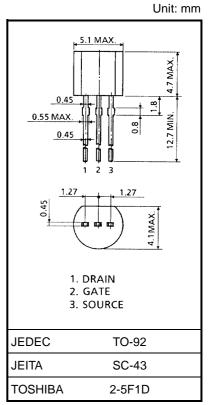
2SK362

For Audio Amplifier, Analog Switch, Constant Current and Impedance Converter Applications

- High breakdown voltage: $V_{GDS} = -50 V$
- High input impedance: $I_{GSS} = -1.0 \text{ nA} (max) (V_{GS} = -30 \text{ V})$
- Low RDS (ON): RDS (ON) = 80 Ω (typ.) (IDSS = 5 mA)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Gate-drain voltage	V _{GDS}	-50	V
Gate current	۱ _G	10	mA
Drain power dissipation	PD	300	mW
Junction temperature	Тј	125	°C
Storage temperature range	T _{stg}	-55~125	°C



Weight: 0.21 g (typ.)

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate cut-off current	I _{GSS}	$V_{GS} = -30$ V, $V_{DS} = 0$			-1.0	nA
Gate-drain breakdown voltage	V (BR) GDS	$V_{DS} = 0, I_G = -100 \ \mu A$	-50	_	_	V
Drain current	I _{DSS} (Note 1)	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0$	1.2		14	mA
Gate-source cut-off voltage	V _{GS (OFF)}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 0.1 \mu\text{A}$	-0.25	_	-1.5	V
Forward transfer admittance	Y _{fs}	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0, \text{ f} = 1 \text{ kHz}$ (Note 2)	5.0	19	_	mS
Input capacitance	C _{iss}	$V_{DS} = 10 \text{ V}, \text{ V}_{GS} = 0, \text{ f} = 1 \text{ MHz}$	_	13	_	pF
Reverse transfer capacitance	C _{rss}	$V_{GD} = -10 V, I_D = 0, f = 1 MHz$	_	3	_	pF
Drain-source ON resistance	R _{DS} (ON)	$V_{DS} = 10 \text{ mV}, V_{GS} = 0 \qquad (\text{Note 2})$	_	80	_	Ω

Note 1: I_{DSS} classification Y: 1.2~3.0 mA, GR: 2.6~6.5 mA, BL: 6~14 mA

Note 2: Condition of the typical value $I_{DSS} = 5 \text{ mA}$

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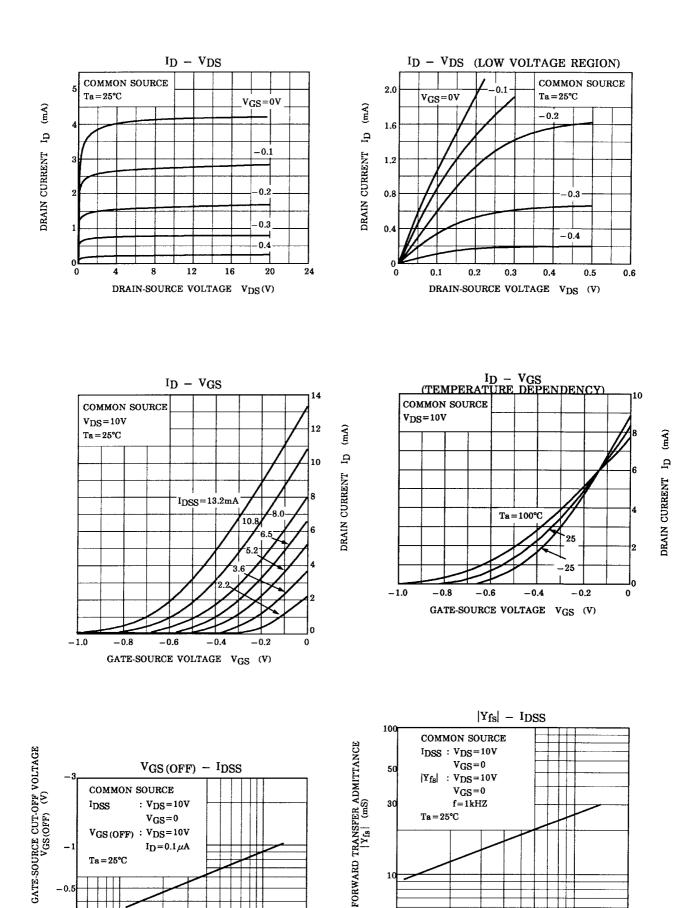
-0.3

0.5

1

3

DRAIN CURRENT IDSS (mA)



20

10

20

10

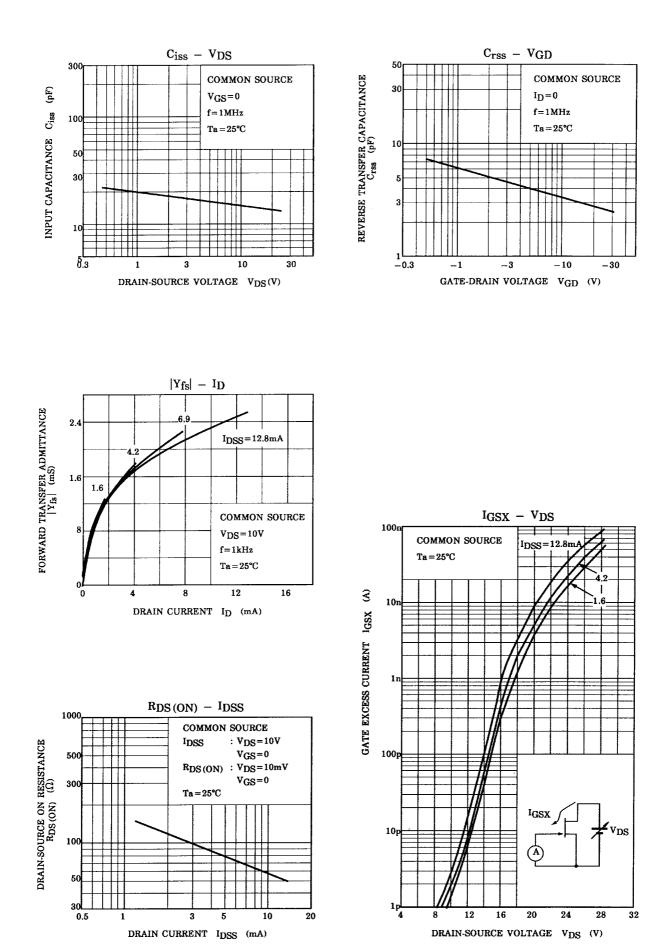
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1

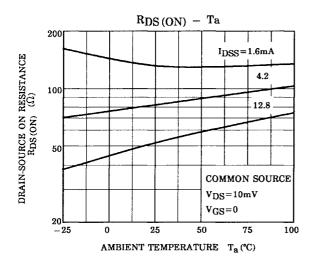
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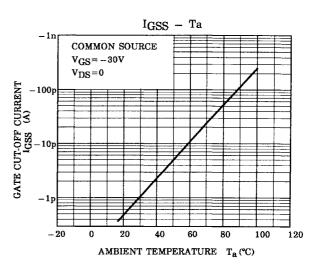
DRAIN CURRENT IDSS (mA)

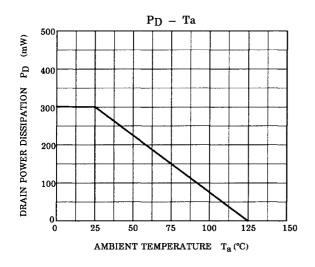
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